# **CPH5505**



http://onsemi.com

# Bipolar Transistor -30V, -3A, Low VCE(sat), PNP Dual CPH5

#### **Applications**

· Relay drivers, lamp drivers, motor drivers, flash

#### **Features**

- · Composite type with two PNP transistors contained in a single package facilitating high-density mounting
- The CPH5505 consists of two chips which are equivalent to the CPH3109 encapsulated in a package
- · Ultrasmall package facilitates miniaturization in end products (mounting height: 0.9mm)

#### **Specifications**

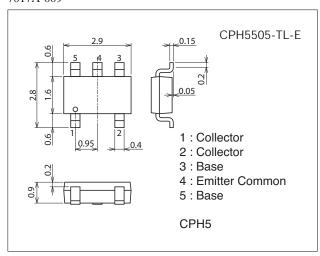
#### Absolute Maximum Ratings at Ta=25°C

| Parameter                    | Symbol           | Conditions  | Ratings     | Unit |
|------------------------------|------------------|---|-------------|------|
| Collector to Base Voltage    | VCBO             |   | -30         | V    |
| Collector to Emitter Voltage | VCEO             |   | -30         | V    |
| Emitter to Base Voltage      | V <sub>EBO</sub> |   | -5          | V    |
| Collector Current            | IC               |   | -3          | Α    |
| Collector Current (Pulse)    | ICP              |   | -5          | Α    |
| Base Current                 | ΙΒ               |   | -600        | mA   |
| Collector Dissipation        | PC               | When mounted on ceramic substrate (600mm <sup>2</sup> ×0.8mm) | 0.9         | W    |
| Total Dissipation            | PT               | When mounted on ceramic substrate (600mm <sup>2</sup> ×0.8mm) | 1.2         | W    |
| Junction Temperature         | Tj               |   | 150         | °C   |
| Storage Temperature          | Tstg             |   | -55 to +150 | °C   |

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

#### **Package Dimensions**

unit : mm (typ) 7017A-009

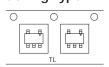


#### Product & Package Information

• Package : CPH5

JEITA, JEDEC : SC-74A, SOT-25
 Minimum Packing Quantity : 3,000 pcs./reel

#### Packing Type: TL



#### Marking



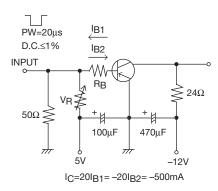
#### **Electrical Connection**



#### Electrical Characteristics at Ta=25°C

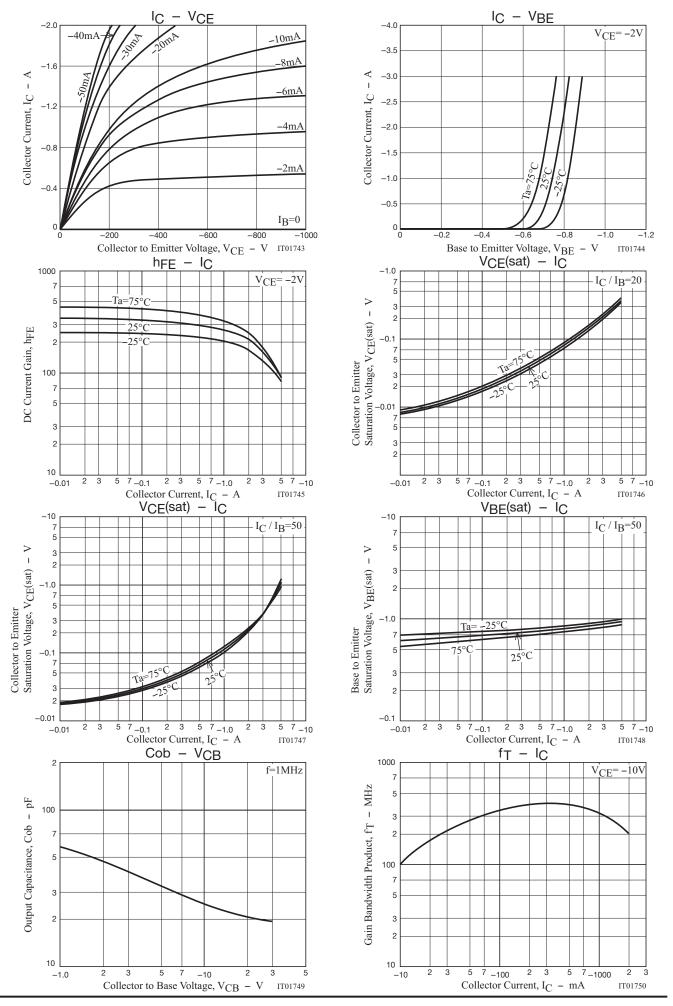
| Parameter                               | Symbol                 | Conditions                                      | Ratings |       |      | Unit  |
|---|------------------------|---|---------|-------|------|-------|
| Parameter                               |                        | Conditions                                      | min     | typ   | max  | Ullit |
| Collector Cutoff Current                | ICBO                   | V <sub>CB</sub> = -30V, I <sub>E</sub> =0A      |         |       | -0.1 | μΑ    |
| Emitter Cutoff Current                  | IEBO                   | V <sub>EB</sub> = -4V, I <sub>C</sub> =0A       |         |       | -0.1 | μΑ    |
| DC Current Gain                         | hFE                    | V <sub>CE</sub> = -2V, I <sub>C</sub> = -500mA  | 200     |       | 560  |       |
| Gain-Bandwidth Product                  | fŢ                     | V <sub>CE</sub> = -10V, I <sub>C</sub> = -500mA |         | 380   |      | MHz   |
| Output Capacitance                      | Cob                    | V <sub>CB</sub> = -10V, f=1MHz                  |         | 25    |      | pF    |
| Collector to Emitter Saturation Voltage | V <sub>CE</sub> (sat)1 | I <sub>C</sub> = -1.5A, I <sub>B</sub> = -30mA  |         | -155  | -230 | mV    |
|   | V <sub>CE</sub> (sat)2 | I <sub>C</sub> = -1.5A, I <sub>B</sub> = -75mA  |         | -105  | -155 | mV    |
| Base to Emitter Saturation Voltage      | V <sub>BE</sub> (sat)  | I <sub>C</sub> = -1.5A, I <sub>B</sub> = -30mA  |         | -0.83 | -1.2 | V     |
| Collector to Base Breakdown Voltage     | V(BR)CBO               | IC= -10μA, IE=0A                                | -30     |       |      | V     |
| Collector to Emitter Breakdown Voltage  | V(BR)CEO               | IC= -1mA, RBE=∞                                 | -30     |       |      | V     |
| Emitter to Base Breakdown Voltage       | V(BR)EBO               | I <sub>E</sub> = -10μA, I <sub>C</sub> =0A      | -5      |       |      | V     |
| Turn-ON Time                            | t <sub>on</sub>        |   |         | 50    |      | ns    |
| Storage Time                            | tstg                   | See specified Test Circuit.                     |         | 270   |      | ns    |
| Turn-OFF Time                           | tf                     |   |         | 25    |      | ns    |

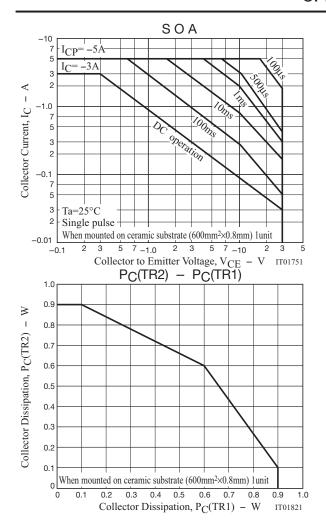
# **Switching Time Test Circuit**

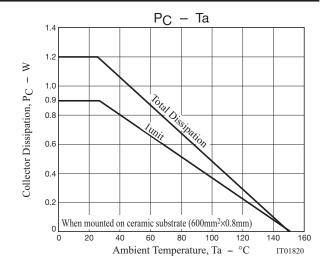


# **Ordering Information**

| Device       | Package | Shipping       | memo    |
|--------------|---------|----------------|---------|
| CPH5505-TL-E | CPH5    | 3,000pcs./reel | Pb Free |

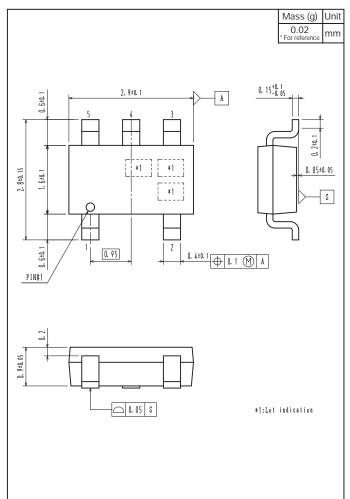




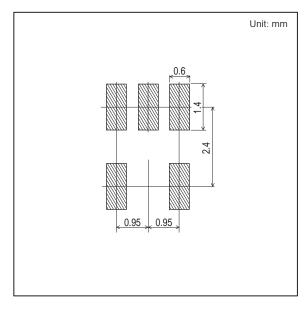


## **Outline Drawing**

CPH5505-TL-E



## Land Pattern Example



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